# P-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

- Low  $r_{DS(on)}$  Provides Higher Efficiency and Extends Battery Life
- Miniature SO-8 Surface Mount Package Saves Board Space
- High power and current handling capability

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	) $r_{DS(on)} m(\Omega)$ $I_D(A)$			
-30	$9 @ V_{GS} = -10V$	-15		
	$13 @ V_{GS} = -4.5V$	-11		



Extended VGS range (±25) for battery pack applications	~			
ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C V	UNLESS OT	1		
Parameter			Maximum	Units
Drain-Source Voltage			-30	V
Gate-Source Voltage		V <sub>GS</sub>	±25	V
	$T_A=25^{\circ}C$	т_	-15	
Continuous Drain Current <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	I <sub>D</sub>	-11	А
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	±50	L
Continuous Source Current (Diode Conduction) <sup>a</sup>			-2.1	А
	$T_A=25^{\circ}C$	PD	3.1	W
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	гD	2.3	vv
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Case <sup>a</sup>	t <= 5 sec	$R_{\theta JC}$	25	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	t <= 5 sec	$R_{\theta JA}$	50	°C/W	

Notes

Surface Mounted on 1" x 1" FR4 Board. a.

Pulse width limited by maximum junction temperature b.

Parameter	Symbol	Test Conditions	Limits			Unit
rarameter	Symbol	Symbol Test Conditions		Тур	Max	Umt
Static						
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \text{ uA}$	-1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 25 V$			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -24 V, V_{GS} = 0 V$			-1	uA
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			-5	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	-50			Α
		$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -13 \text{ A}$			9	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -11 \text{ A}$			13	mΩ
		$V_{GS} = -10 \text{ V}, I_D = -13 \text{ A}, TJ = 55^{\circ}\text{C}$			11	
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = -5 V, I_D = -13 A$		44		S
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 2.1$ A, $V_{\rm GS} = 0$ V		-0.7		V
Dynamic <sup>b</sup>						
Total Gate Charge	Qg	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V},$ $I_D = -13 \text{ A}$		37.0		nC
Gate-Source Charge	Q <sub>gs</sub>			10.0		
Gate-Drain Charge	Q <sub>gd</sub>			14.5		
Switching						-
Turn-On Delay Time	t <sub>d(on)</sub>			19		nS
Rise Time	t <sub>r</sub>	$V_{DD}$ = -15 V, $R_L$ = 6 $\Omega$ , ID = -1 A,		11		
Turn-Off Delay Time	t <sub>d(off)</sub>	VGEN = -10 V		121		
Fall-Time	t <sub>f</sub>			68		

Notes

- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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